

# MBR6050PT THRU MBR60100PT

60.0 AMPS. Schottky Barrier Rectifiers



Voltage Range 50 to 100 Volts Current 60.0 Amperes

TO-3P/TO-247AD

#### **Features**

- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon rectifier, majority carrier conduction
- ♦ Low power loss, high efficiency
- High current capability, low forward voltage drop
- ♦ High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ♦ Guardring for overvoltage protection
- High temperature soldering guaranteed: 260°C/10 seconds,0.17"(4.3mm)from case

### **Mechanical Data**

- ♦ Cases: JEDEC TO-3P/TO-247AD molded plastic body
- ♦ Terminals: Leads solderable per MIL-STD-750, Method 2026
- ♦ Polarity: As marked
- Mounting position: Any
- ♦ Mounting torque: 10 in. lbs. max
- ♦ Weight: 0.2 ounce, 5.6 grams

#### 203(5,16) .323(8.2) .225(5.7) .323(8.2)

Dimensions in inches and (millimeters)

## **Maximum Ratings and Electrical Characteristics**

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBR6050PT	MBR6060PT	MBR60100PT	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	60	100	V
Maximum RMS Voltage	$V_{RMS}$	35	42	70	V
Maximum DC Blocking Voltage	$V_{DC}$	50	60	100	V
Maximum Average Forward Rectified Current at Tc=125°C	I <sub>(AV)</sub>	60			А
Peak Repetitive Forward Current (Rated V <sub>R</sub> , Square Wave, 20KHz) at Tc=120°C	I <sub>FRM</sub>	60.0			Α
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I <sub>FSM</sub>	500			Α
Peak Repetitive Reverse Surge Current (Note 1)	$I_{RRM}$	1.0			Α
Maximum Instantaneous Forward Voltage at (Note 2) $I_F=30A$ , Tc=25 $^{\circ}$ C $I_F=30A$ , Tc=125 $^{\circ}$ C	V <sub>F</sub>	0.72 0.62			V
Maximum Instantaneous Reverse Current @Tc=25°C at Rated DC Blocking Voltage Per Leg @ Tc=125°C (Note 1)	I <sub>R</sub>	1.0 100.0			mA mA
Voltage Rate of Change at (Rated V <sub>R</sub> )	dV/dt	1,000			V/uS
Typical Thermal Resistance Per Leg (Note 3)	$R\theta JC$	1.2			€\M
Operating Junction Temperature Range	TJ	-65 to +150			${\mathfrak C}$
Storage Temperature Range	Tstg	-65 to +175			${\mathfrak C}$

- Notes: 1. 2.0us Pulse Width, f=1.0 KHz
  - 2. Pulse Test: 300us Pulse Width, 1% Duty Cycle
  - 3. Thermal Resistance from Junction to Case Per Leg



